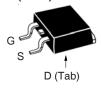


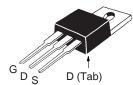
PolarP[™] Power MOSFETs

P-Channel Enhancement Mode Avalanche Rated IXTA52P10P IXTP52P10P IXTQ52P10P IXTH52P10P $V_{DSS} = -100V$ $I_{D25} = -52A$ $R_{DS(on)} \le 50m\Omega$



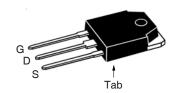




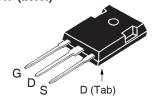




TO-3P (IXTQ)



TO-247 (IXTH)



G = Gate	D	= Drain
S = Source	Tab	= Drain

Symbol	Test Conditions	Maximum Ratings		
V _{DSS}	T _J = 25°C to 150°C	-100	V	
V _{DGR}	$T_J = 25^{\circ}C$ to 150°C, $R_{GS} = 1M\Omega$	-100	V	
V _{GSS}	Continuous	±20	V	
V _{GSM}	Transient	±30	V	
I _{D25}	T _C = 25°C	- 52	A	
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	-130	Α	
I _A	T _C = 25°C	- 52	A	
E _{as}	$T_{c} = 25^{\circ}C$	1.5	J	
dv/dt	$I_{_{\mathrm{S}}} \le I_{_{\mathrm{DM}}}, V_{_{\mathrm{DD}}} \le V_{_{\mathrm{DSS}}}, T_{_{\mathrm{J}}} \le 150^{\circ}\mathrm{C}$	10	V/ns	
P_{D}	T _C = 25°C	300	W	
T _J T _{JM} T _{stg}		-55 +150 150 -55 +150	0° 0° 0°	
T _L T _{SOLD}	1.6mm (0.062 in.) from Case for 10s Plastic body for 10s	300 260	°C °C	
M _d	Mounting Torque (TO-3P,TO-220,TO-247)	1.13/10	Nm/lb.in.	
Weight	TO-263 TO-220 TO-3P TO-247	2.5 3.0 5.5 6.0	g g g	

Features

- International Standard Packages
- Fast Intrinsic Diode
- Dynamic dv/dt Rated
- Avalanche Rated
- Rugged PolarP™ Process
- $^{\bullet}$ Low Q_{G} and $\mathrm{R}_{\mathrm{ds(on)}}$
- Low Drain-to-Tab Capacitance
- Low Package Inductance

Advantages

- Easy to Mount
- Space Savings
- High Power Density

Applications

- High-Side Switching
- Push-Pull Amplifiers
- DC Choppers
- Current Regulators
- Automatic Test Equipment

Test Conditions Symbol **Characteristic Values** (T₁ = 25°C, Unless Otherwise Specified) Max. Min. Typ. BV_{DSS} $V_{GS} = 0V, I_{D} = -250\mu A$ -100 $V_{\underline{G\underline{S(th)}}}$ $V_{DS} = V_{GS}, I_{D} = -250 \mu A$ - 2.0 V - 4.0 $V_{GS} = \pm 20V, V_{DS} = 0V$ ±100 nA l_{GSS} $V_{DS} = V_{DSS}, V_{GS} = 0V$ -10 μA I_{DSS} T_{.1} = 125°C -150 μA $\boldsymbol{R}_{DS\underline{(on)}}$ $V_{GS} = -10V, I_{D} = 0.5 \cdot I_{D25}$, Note 1 $50~\text{m}\Omega$



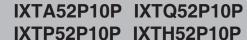
Symbol	Test Conditions	Characteristic Values			
$(T_J = 25^{\circ}C, l)$	Unless Otherwise Specified)	Min.	Тур.	Max.	
g _{fs}	$V_{DS} = -10V, I_{D} = 0.5 \cdot I_{D25}, \text{ Note 1}$	12	20	S	
C _{iss}			2845	pF	
C _{oss}	$V_{GS} = 0V, V_{DS} = -25V, f = 1MHz$		1015	pF	
C _{rss}			275	pF	
t _{d(on)}	Resistive Switching Times		22	ns	
t,	•		29	ns	
t _{d(off)}	$V_{GS} = -10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		38	ns	
t _f)	$\int R_{\rm G} = 3.3\Omega \text{ (External)}$		22	ns	
$Q_{g(on)}$			60	nC	
Q _{gs}	$V_{GS} = -10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$		17	nC	
Q_{gd}			23	nC	
R _{thJC}				0.42 °C/W	
R _{thCS}	(TO-3P)(TO-247)		0.21	°C/W	
	(TO-220)		0.50	°C/W	

Source-Drain Diode

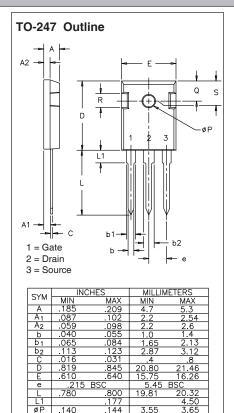
Note

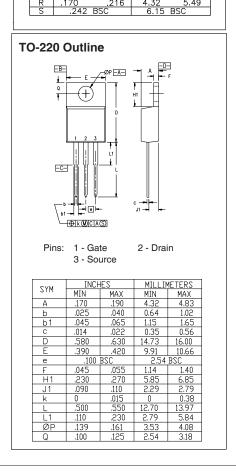
Symbol	Test Conditions	Characteristic Values			
(T _J = 25°C, Unless Otherwise Specified)		Min.	Тур.	Max	
Is	$V_{GS} = 0V$			- 52	Α
I _{SM}	Repetitive, Pulse Width Limited by $T_{_{JM}}$			- 200	Α
V _{SD}	$I_F = -26A, V_{GS} = 0V, \text{ Note 1}$			- 3.5	V
t _{rr} Q _{RM} I _{RM}	$ \begin{cases} & I_{_F} = \text{- 26A, -di/dt} = \text{-100A/}\mu\text{s} \\ & V_{_{B}} = \text{- 50V, V}_{_{GS}} = \text{0V} \end{cases} $		120 0.53 - 8.9		ns μC A

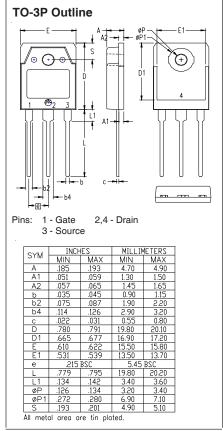
1: Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.











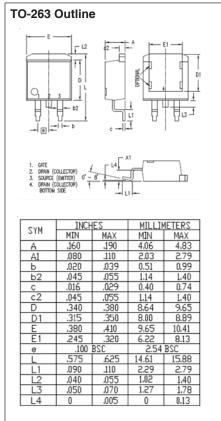




Fig. 1. Output Characteristics @ $T_J = 25^{\circ}C$

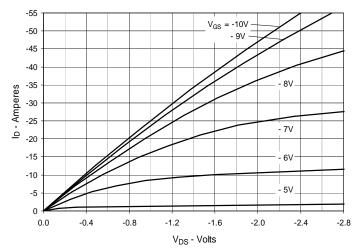


Fig. 2. Extended Output Characteristics @ T_J = 25°C

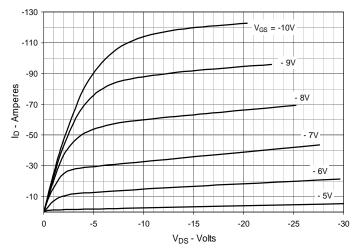


Fig. 3. Output Characteristics @ T_J = 125°C

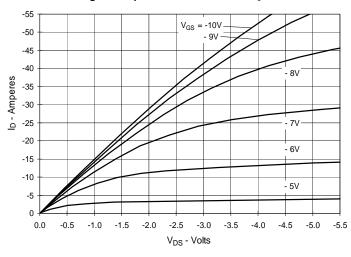


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = -26A$ Value vs. Junction Temperature

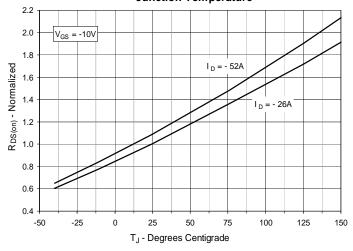


Fig. 5. $R_{DS(on)}$ Normalized to $I_D = -26A$ Value vs.

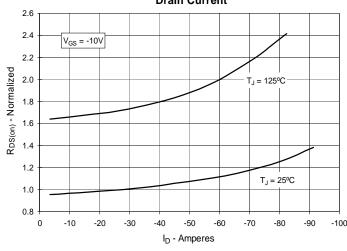
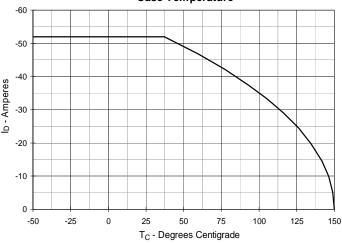


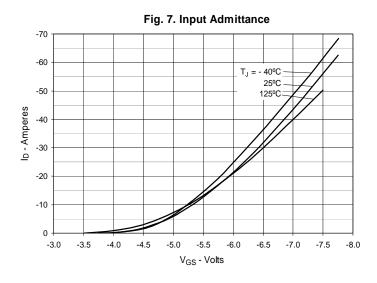
Fig. 6. Maximum Drain Current vs.

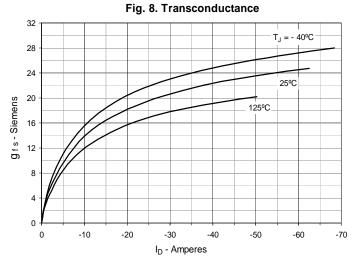
Case Temperature

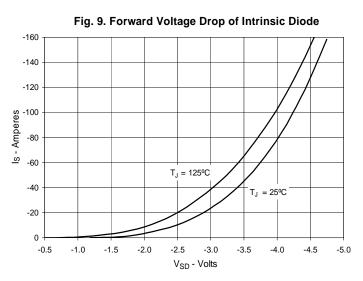


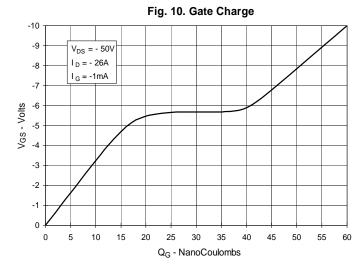
IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

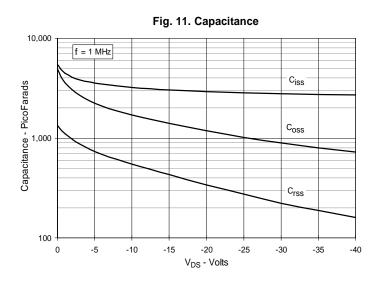


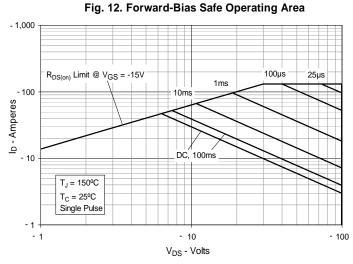














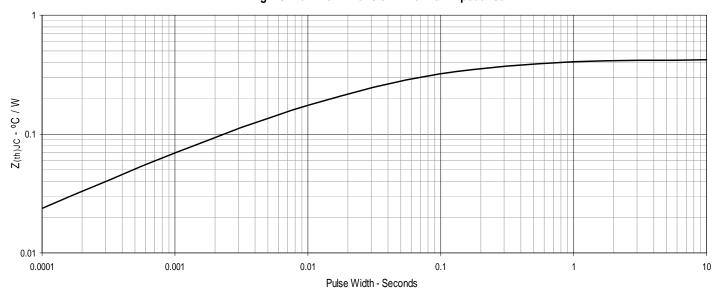


Fig. 13. Maximum Transient Thermal Impedance

